

Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Breakdown Voltage, BV _{CEO}	350	V_P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	Α
Input Power Dissipation ¹	150	mW
Phototransistor Power Dissipation ²	150	mW
Isolation Voltage, Input to Output	5000	V _{rms}
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

 $^{^{1}\,}$ Derate linearly 1.33 mW / $^{\circ}\text{C}\,$

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

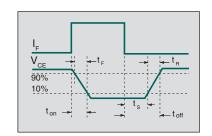
Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manfacturing testing requirements.

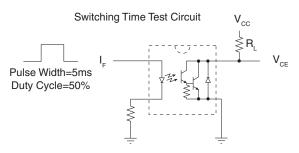
Electrical Characteristics @ 25°C

Parameters	Conditions	Symbol	Min	Тур	Max	Units
Output Characteristics						
Phototransistor Breakdown Voltage	I _{CEO} =100μA	BV _{CEO}	350	-	-	V _P
Emitter-Collector Breakdown Voltage	I _E =0.1mA	BV _{ECO}	0.3	-	-	V
Phototransistor Output (Dark) Current	V _{CEO} =200V, I _F =0mA	I _{CEO}	-	-	100	nA
Saturation Voltage	I _C =10mA, I _F =1mA	V	-	-	1	V
	$I_{C}=100$ mA, $I_{F}=10$ mA	V _{CE(Sat)}	-	-	1.2	
Current Transfer Ratio	I _F =1mA, V _{CE} =1V	CTR	1000	5500	8000	%
Output Capacitance	V _{CEO} =50V, f=1MHz	C _{OUT}	-	13	-	pF
Input Characteristics						
Input Control Current	I _C =10mA, V _{CE} =1V	l _F	-	0.07	1	mA
Input Voltage Drop	I _F =5mA	V_{F}	0.9	1.2	1.4	V
Input Reverse Current	V _R =5V	I _R	-	-	10	μΑ
Common Characteristics					•	
Input to Output Capacitance	-	C _{I/O}	-	3	-	pF

Switching Characteristics @ 25°C

Characteristic	Symbol	Test Condition	Тур	Units
Rise Time	t _R		40	
Fall Time	t _F	V _{CC} =10V	2.6	
Turn-On Time	t _{on}	I _F =10mA	2.75	
Storage Time	t _s	$R_L=100\Omega$	20	
Turn-Off Time	t _{off}		60	μS
Turn-On Time	t _{on}	V _{CC} =10V	1	
Storage Time	t _s	I _F =16mA	40	
Turn-Off Time	t _{off}	$R_L=180\Omega$	80	

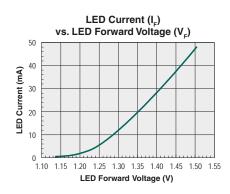


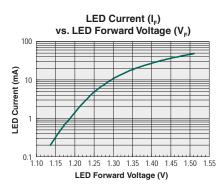


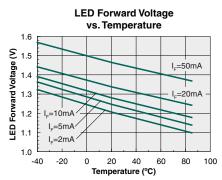
² Derate linearly 1.5 mW / °C

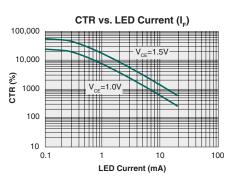


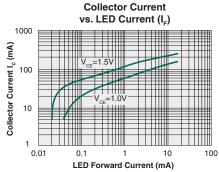
PERFORMANCE DATA @25°C (Unless Otherwise Noted)*

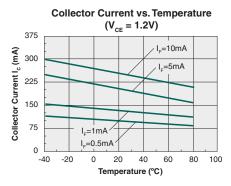


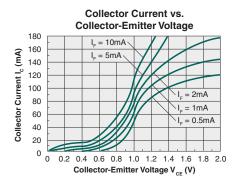


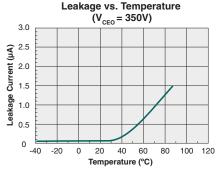


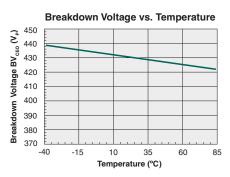


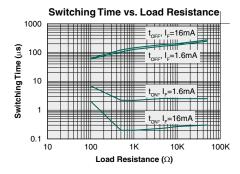












^{*}The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.



Manufacturing Information

Moisture Sensitivity

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, IPC/JEDEC J-STD-020, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating	
CPC1301G	MSL 1	
CPC1301GR	MSL 3	

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Soldering Profile

Provided in the table below is the Classification Temperature (T_C) of this product and the maximum dwell time the body temperature of this device may be above (T_C - 5)°C. The classification temperature sets the Maximum Body Temperature allowed for this device during lead-free reflow processes. Additionally, for the CPC1301GR, the solder reflow profile given in Technical Brief TB-200 "Pb-Free Solder Reflow Profile for Select Devices" must be followed. For the through-hole device, CPC1301G, and any other processes, the guidelines of J-STD-020 must be observed.

Device	Maximum Body Temperature (T _c)	Time
CPC1301GR	250°C	15 seconds

Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include, but are not limited to: using a low pressure wash and providing a follow-up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device, and should not be used. Additionally, the device must not be exposed to flux or solvents that are Chlorine- or Fluorine-based.



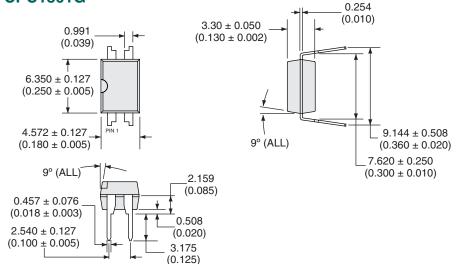




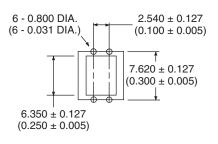


MECHANICAL DIMENSIONS

CPC1301G

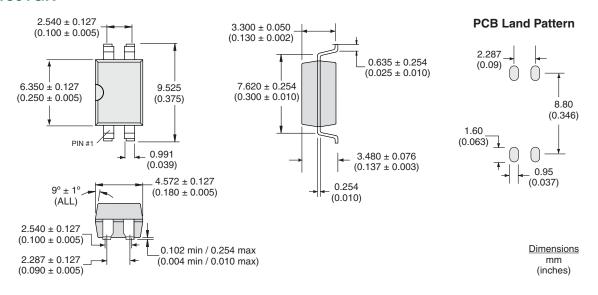


PC Board Pattern (Top View)



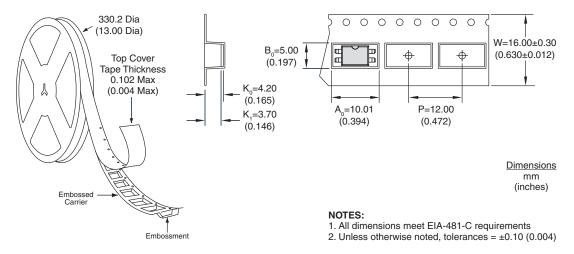
Dimensions mm (inches)

CPC1301GR





CPC1301GRTR Tape & Reel



For additional information please visit our website at: www.ixysic.com

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